

66170

**GULL WING HERMETICALLY SEALED,
SINGLE CHANNEL OPTOCOUPLER
(Electrically Similar To 6N140)**

Mii

OPTOELECTRONIC PRODUCTS DIVISION

Features:

- High current transfer ratio: 1000% typical
 - 1500 Vdc isolation test voltage
 - Low input current requirement: 0.5mA
 - Low power consumption
 - High radiation immunity

Applications:

- Military and space
 - High reliability systems
 - Voltage level shifting
 - Isolated receiver input
 - Communication systems
 - Medical systems

DESCRIPTION

The **66170** single channel optocoupler consists of an LED optically coupled to a high gain photon detector. This unique device provides high CTR and low leakage currents over the full military temperature range (-55°C to +125°C). The 66170 is an 10 pin gull wing hermetically sealed package and is available in standard and screened versions or tested to customer specifications.

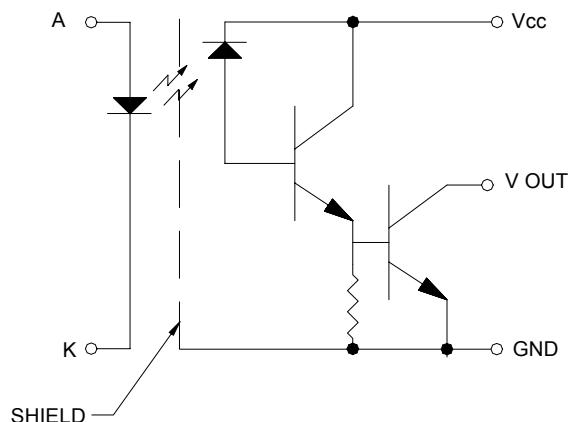
ABSOLUTE MAXIMUM RATINGS

Storage Temperature.....	-65°C to +150°C
Operating Free-Air Temperature Range	-55°C to +125°C
Lead Solder Temperature.....	260°C for 10s (1.6mm below seating plane)
Peak Forward Input Current	40mA (<1ms duration)
Average Forward Input Current ..(Derate I_F at a rate of 0.05 mA/°C)	20mA
Reverse Input Voltage	5V
Supply Voltage - V_{CC} ..(The lowest total I_{OH} over temperature is developed by keeping V_{CC} as low as possible, but greater than 2.0V)	-0.5 TO 20V Output
Output Current - I_O	40mA
Output Power Dissipation (Collector output power +1/4 of the total supply power is total output power. Derate @ rate of 1.66mA/°C above 110°C)	50mW
Output Voltage - V_O(The lowest total I_{OH} over temperature is developed by keeping V_{CC} as low as possible, but greater than 2.0V)	-0.5 TO 20V

Package Dimensions

Schematic Diagram

**CONTACT FACTORY
FOR PACKAGE
AND PIN OUT
INFORMATION**



ELECTRICAL CHARACTERISTICS $T_a = -55^\circ C$ to $125^\circ C$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Current Transfer Ratio	CTR	300	1000		%	$I_F = 0.5\text{mA}$, $V_O = 0.4\text{V}$, $V_{CC} = 4.5\text{V}$	1
		300	750		%	$I_F = 1.6\text{mA}$, $V_O = 0.4\text{V}$, $V_{CC} = 4.5\text{V}$	1
		200	400		%	$I_F = 5.0\text{mA}$, $V_O = 0.4\text{V}$, $V_{CC} = 4.5\text{V}$	1
Logic Low Output Voltage	V_{OL}		0.1	0.4	V	$I_F = 0.5\text{mA}$, $I_{OL} = 1.5\text{mA}$, $V_{CC} = 4.5\text{V}$	
			0.2	0.4	V	$I_F = 5.0\text{mA}$, $I_{OL} = 10\text{mA}$, $V_{CC} = 4.5\text{V}$	
Logic High Output Current	I_{OH}		.005	250	μA	$I_F = 2\mu\text{A}$, $V_O = V_{CC} = 18\text{V}$	2
Logic High Supply Current	I_{CCH}		.010	40	μA	$I_F = 0\text{mA}$, $V_{CC} = 18\text{V}$	
Low Level Supply Current	I_{CCL}		0.8	2	mA	$I_F = 1.6\text{mA}$, $V_{CC} = 18\text{V}$	
Input Forward Voltage	V_F		1.4	1.8	V	$I_F = 1.6\text{mA}$	
Input Reverse Breakdown Voltage	BV_R	5			V	$I_R = 10\mu\text{A}$	
Input-Output Insulation Leakage Current	I_{I-O}			1.0	μA	$V_{I-O} = 1500\text{Vdc}$, Relative Humidity = 45% $t_A = 25^\circ C$, $t = 5\text{s}$	3
Propagation Delay Time To High Output Level	t_{PLH}		5	60	μs	$I_F = 0.5\text{mA}$, $V_{CC} = 5.0\text{V}$, $R_L = 4.7\text{k}\Omega$	
			4	20	μs	$I_F = 5\text{mA}$, $V_{CC} = 5.0\text{V}$, $R_L = 680\text{k}\Omega$	
Propagation Delay Time To Low Output Level	t_{PHL}		8	100	μs	$I_F = 0.5\text{mA}$, $V_{CC} = 5.0\text{V}$, $R_L = 4.7\text{k}\Omega$	
			2	5	μs	$I_F = 5\text{mA}$, $V_{CC} = 5.0\text{V}$, $R_L = 680\text{k}\Omega$	

TYPICAL CHARACTERISTICS $T_a = 25^\circ C$, $V_{CC} = 5\text{V}$ Each Channel

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Input Capacitance	C_{IN}		60		pF	$V_F = 0$, $f = 1\text{MHz}$, $t_a = 25^\circ C$	
Capacitance (Input-Output)	C_{I-O}		1.5		pF	$f = 1\text{MHz}$, $t_a = 25^\circ C$	4
Input Diode Temperature Coefficient	$\frac{\Delta V_F}{\Delta T_A}$		-1.8		mV/ $^\circ C$	$I_F = 1.6\text{mA}$	
Resistance (Input-Output)	R_{I-O}		10^{12}		Ω	$V_{I-O} = 500\text{V}$, $t_a = 25^\circ C$	4
Common Mode Transient immunity at High Output Level	CM_H	500	1000		V/ μs	$V_{CM} = 50\text{V P-P}$, $V_{CC} = 5.0\text{V}$, $R_L = 1.5\text{k}\Omega$, $I_F = 0\text{mA}$ $t_a = 25^\circ C$	5, 7
Common Mode Transient Immunity at Low Output Level	CM_L	500	1000		V/ μs	$V_{CM} = 50\text{V P-P}$, $V_{CC} = 5.0\text{V}$, $R_L = 1.5\text{k}\Omega$, $I_F = 1.6\text{mA}$ $t_a = 25^\circ C$	6, 7

NOTES:

1. CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I_O , to the forward LED input current., I_F , times 100%.
2. $I_F = 2\mu\text{A}$ for channel under test. For all other channels, $I_F = 10\text{mA}$.
3. Device considered a two-terminal device. Pins 1-6 and 16 are shorted together and pins 7-14 are shorted together.
4. Measured between each input pair shorted together.
5. CM_H is the maximum tolerable common mode transient to assure that the output will remain in a high logic state (i.e. $V_O > @.0\text{V}$).
6. CM_L is the maximum tolerable common mode transient to assure that the output will remain in a low logic state (i.e. $V_O < 0.8\text{V}$).
7. In applications where dv/dt may exceed 50,000 V/ μs (such as static discharge) a series resistor, R_{CC} , should be included to protect the detector ICs from destructively high surge currents. The recommended value is $R_{CC} = \frac{1\text{V}}{0.6I_F \text{ (mA)}}$

RECOMMENDED OPERATING CONDITIONS:

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level	I_{FL}	0	2	μA
Input Current, High Level	I_{FH}	0.5	5	mA
Supply Voltage	V_{CC}	2.0	18	V

SELECTION GUIDE

PART NUMBER	PART DESCRIPTION
66170-000	Single Channel optocoupler, full mil-temp (-55° to +125° $^\circ C$) with 100% device screening
66170-002	Single Channel optocoupler, military operating range (-55° to +125° $^\circ C$)
66170-003	Single Channel optocoupler, commercial (0° to 70° $^\circ C$)
66170-004	Single Channel optocoupler, extended temperature range (-40° to +85° $^\circ C$)